



MT130N15A

主要参数 MAIN CHARACTERISTICS

I_D	130A
V_{DSS}	150V
$R_{dson-max}$ (@ $V_{gs}=10V$)	8.5m Ω
Q_g-typ	63nC

用途

- 电信与工业领域隔离 DC/DC 转换
- 同步整流领域 DC/DC 与 AC/DC 转换

产品特性

- 低栅极电荷
- 低 R_{dson}
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

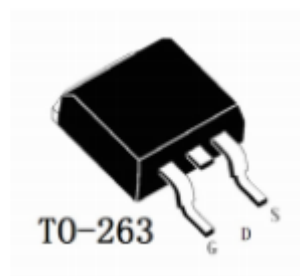
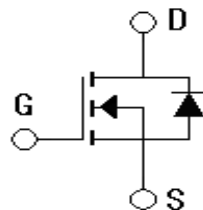
APPLICATIONS

- Isolated DC/DC Converters in Telecom and Industrial
- Synchronous Rectification in DC/DC and AC/DC Converters

FEATURES

- Low gate charge
- Low R_{dson}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
MT130N15A-S-B	MT130N15A-S-BR	MT130N15A-S-A	MT130N15A-S-AR	MT130N15A	TO-263





绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
		MT130N15A	
最高漏极-源极直流电压 Drain-Source Voltage	V_{DSS}	150	V
连续漏极电流 Drain Current -continuous	I_D T=25°C	130*	A
	I_D T=100°C	81*	A
最大脉冲漏极电流 (注1) Drain Current - pulse (note 1)	I_{DM}	480*	A
最高栅源电压 Gate-Source Voltage	V_{GSS}	±20	V
单脉冲雪崩能量 (注2) Single Pulsed Avalanche Energy (note 2)	E_{AS}	324	mJ
雪崩电流 (注1) Avalanche Current (note 1)	I_{AS}	36	A
耗散功率 Power Dissipation	P_D T _C =25°C -Derate above 25°C	227	W
		0.85	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T _L	300	°C

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature





电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
关态特性 Off –Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	150	-	-	V
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=80V, V_{GS}=0V,$ $T_C=25^\circ C$	-	-	1	μA
		$V_{DS}=80V, V_{GS}=0V,$ $T_C=125^\circ C$	-	-	10	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=20V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-20V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	3.0	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=50A$	-	7.0	8.5	m Ω
正向跨导 Forward Transconductance	g_{fs}	$V_{DS} = 5V, I_D=50A$ (note 4)	-	91.8	-	S
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	$V_{DS}=75V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	4217	-	pF
输出电容 Output capacitance	C_{oss}		-	512	-	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	15	-	pF





电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_d(\text{on})$	$V_{DD}=75V, I_D=100A, R_G=2.7\Omega$ $V_{GS}=10V$ (note 3, 4)	-	11	-	ns
上升时间 Turn-On rise time	t_r		-	107	-	ns
延迟时间 Turn-Off delay time	$t_d(\text{off})$		-	54	-	ns
下降时间 Turn-Off Fall time	t_f		-	102	-	ns
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=75V,$ $I_D=50A$ $V_{GS}=10V$ (note 3, 4)	-	63	-	nC
栅-源电荷 Gate-Source charge	Q_{gs}		-	21	-	nC
栅-漏电荷 Gate-Drain charge	Q_{gd}		-	15	-	nC
栅极电阻 Gate Resistance	R_G	$V_{GS}=0V, V_{DS}=0V, f=1\text{MHz}$		5.5		Ω
漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$T_J=25^\circ\text{C}, V_{GS}=0V,$ $I_S=50A$	-	0.86	1.4	V
反向恢复时间 Reverse recovery time	t_{rr}	$I_S=100A$	-	100	-	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}	$dI_F/dt=100A/\mu\text{s}$ (note 3)	-	451	-	nC

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max	单 位 Unit
		MT130N15A	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.60	$^\circ\text{C/W}$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	$^\circ\text{C/W}$

注释:

- 1: 脉冲宽度由最高结温限制
- 2: $V_{DD}=50V, L=0.5\text{mH}, R_G=25\Omega, I_{AS}=36A$ 起始结温
 $T_J=25^\circ\text{C}$
- 3: 脉冲测试: 脉冲宽度 $\leq 300\mu\text{s}$, 占空比 $\leq 2\%$
- 4: 基本与工作温度无关

Notes:

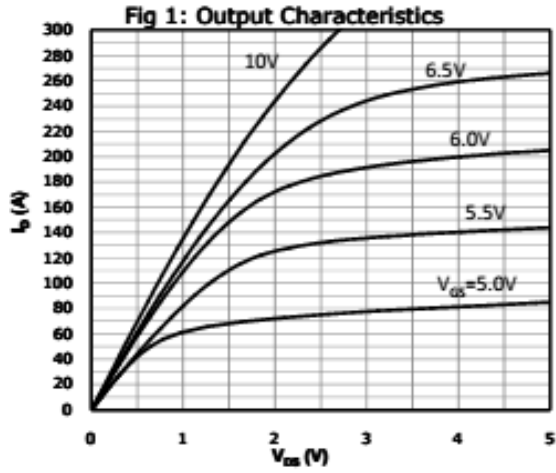
- 1: Pulse width limited by maximum junction temperature
- 2: $V_{DD}=50V, L=0.5\text{mH}, R_G=25\Omega, I_{AS}=36A$ Starting
 $T_J=25^\circ\text{C}$
- 3: Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$
- 4: Essentially independent of operating temperature



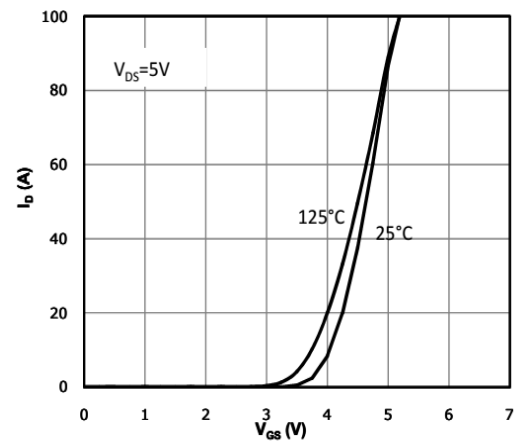


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

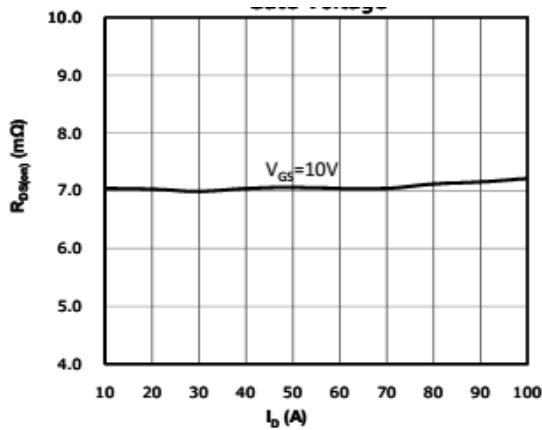
On-Region Characteristics



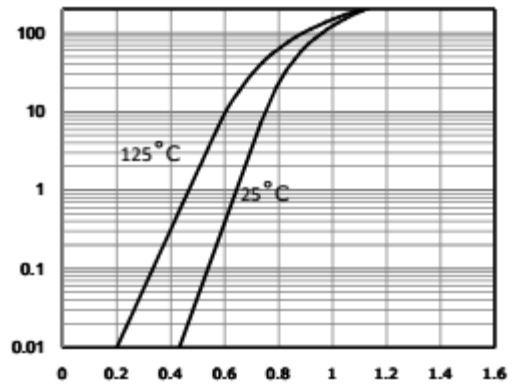
Transfer Characteristics



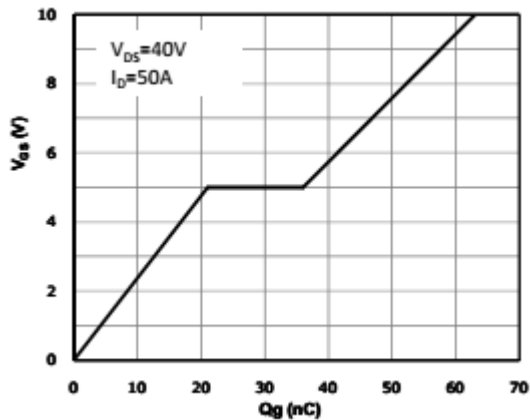
On-Resistance Variation vs. Drain Current



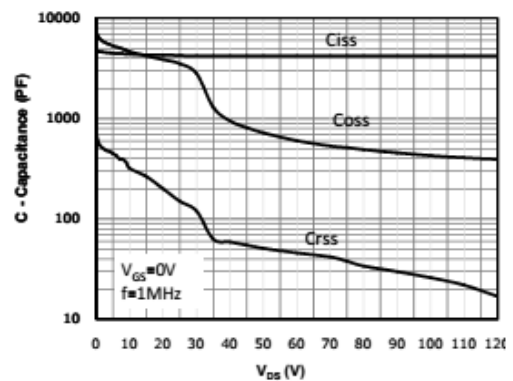
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics



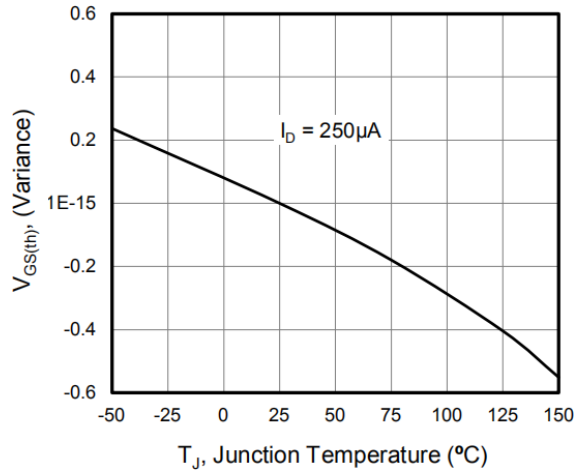
Gate Charge Characteristics



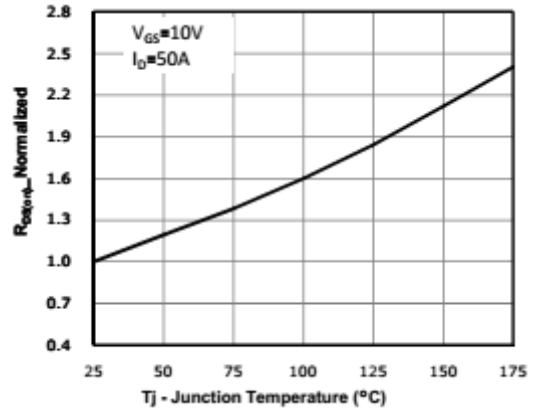


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

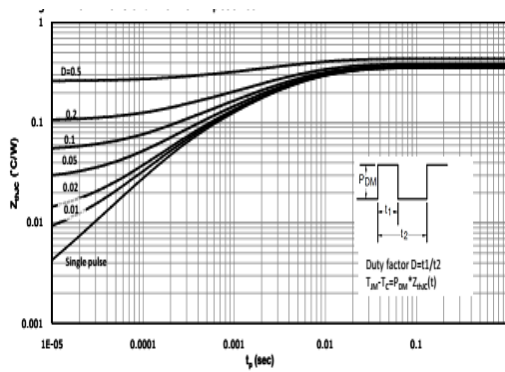
Threshold Voltage Variation vs. Temperature



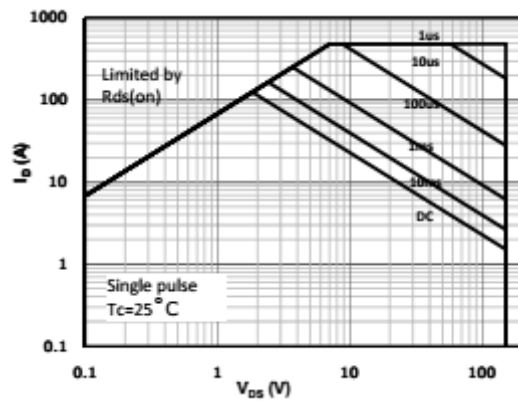
On-Resistance Variation vs. Temperature



Transient Thermal Response Curve For MT130N15A



Safe Operating Area

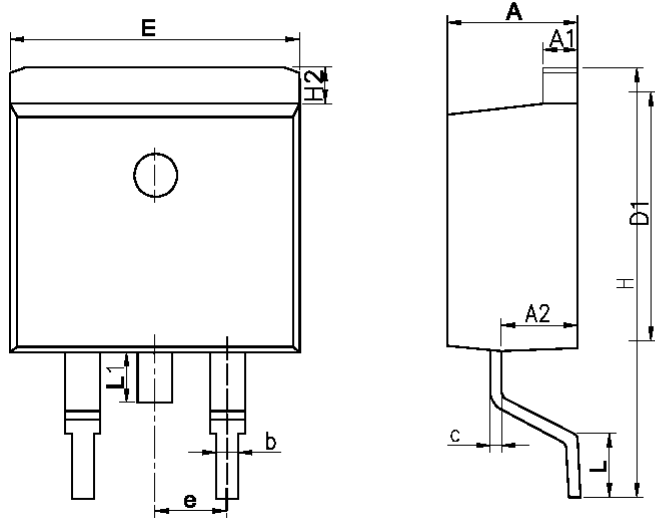




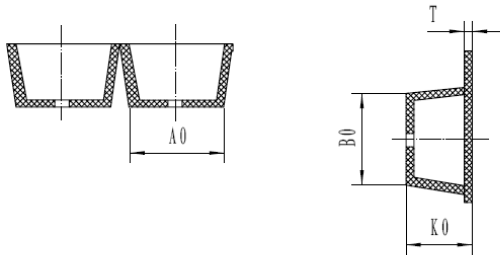
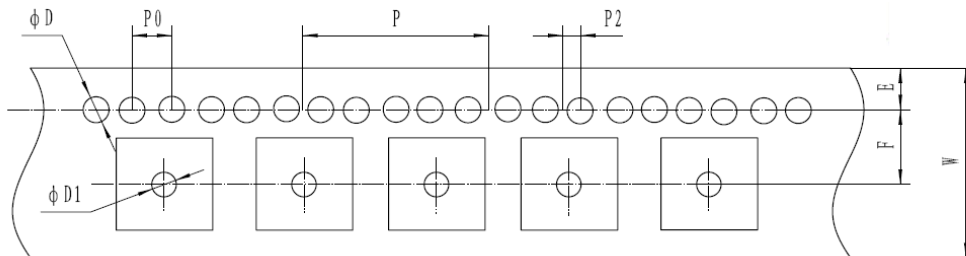
外形尺寸 PACKAGE MECHANICAL DATA

TO-263

单位 Unit: mm



SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.28	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70



产品尺寸规格 (UNIT: mm)					
规格	W	A0	E	F	D
尺寸	24 ± 0.3	10.9 ± 0.1	1.75 ± 0.1	11.5 ± 0.1	1.5 + 0.1/-0
规格	D1	P0	P2	P	T
尺寸	1.5 + 0.1/-0	4 ± 0.1	2 ± 0.1	16 ± 0.1	0.35 ± 0.05
规格	K0	B0			
尺寸	4.9 ± 0.1	16.0 ± 0.1			



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